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U.S. UTILITY Patent Application

PATENT NUMBER and
ISSUE DATE

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10034163	12/27/2001	438	3	28123	S. FOONG

**APPLICANTS: Jeon Joong;

2823

**CONTINUING DATA VERIFIED:

** FOREIGN APPLICATIONS VERIFIED:

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	
Foreign priority claimed 35 USC 119 conditions met		<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input type="checkbox"/> no	ATTORNEY DOCKET NO
Verified and Acknowledged Examiner's initials			G0518
TITLE : Preparation of stack high-K gate dielectrics with nitrided layer			
U.S.DEP'T. OF COMM /PAT.& TM-PTO-436L(Rev 12-94)			

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G
		Assistant Examiner	
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs.Drwg.
		Primary Examiner	
		PREPARED FOR ISSUE	
<input type="checkbox"/> TERMINAL DISCLAIMER		Application Examiner	
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